NSN 5961-00-814-7635

Semiconductor Device Set - Page 1 of 1



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Inc	losure	Mata	rial.
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Metal all semiconductor device diode and glass all semiconductor device diode

Overall Length:

0.560 inches all semiconductor device diode

Terminal Length:

1.250 inches all semiconductor device diode

Overall Diameter:

0.215 inches all semiconductor device diode and 0.225 inches all semiconductor device diode

Function For Which Designed:

Zener diode

Electrode Internally-electrically Connected To Case:

Cathode all semiconductor device diode

Component Function Relationship:

Matched

Component Name And Quantity:

2 semiconductor device diode

Mounting Method:

Terminal all semiconductor device diode

Features Provided:

Hermetically sealed case

Current Rating Per Characteristic:

18.00 milliamperes all primaries horsepower metric all semiconductor device diode and 45.00 milliamperes repetitive peak forward current all semiconductor device diode

Power Rating Per Characteristic:

0.75 watts any acceptable preset all semiconductor device diode

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction all semiconductor device diode

Special Features:

Set selected for total voltage of 28.6 p/m 1 pct.

Terminal Type And Quantity:

2 uninsulated wire lead all semiconductor device diode

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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